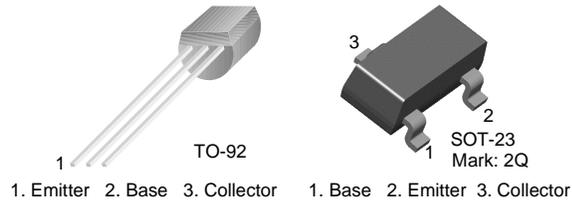


## 2N5086/2N5087/MMBT5087

### PNP General Purpose Amplifier

- This device is designed for low level, high gain, low noise general purpose amplifier applications at collector currents to 50mA.



### Absolute Maximum Ratings\* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	-50	V
$V_{CBO}$	Collector-Base Voltage	-50	V
$V_{EBO}$	Emitter-Base Voltage	-3.0	V
$I_C$	Collector current - Continuous	-100	mA
$T_J, T_{stg}$	Junction and Storage Temperature	-55 ~ +150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- These ratings are based on a maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units	
<b>Off Characteristics</b>						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage *	$I_C = -1.0\text{mA}, I_B = 0$	-50		V	
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -100\mu\text{A}, I_E = 0$	-50		V	
$I_{CEO}$	Collector Cutoff Current	$V_{CB} = -10\text{V}, I_E = 0$ $V_{CB} = -35\text{V}, I_E = 0$		-10 -50	nA nA	
$I_{CBO}$	Emitter Cutoff Current	$V_{EB} = -3.0\text{V}, I_C = 0$		-50	nA	
<b>On Characteristics</b>						
$h_{FE}$	DC Current Gain	$I_C = -100\mu\text{A}, V_{CE} = -5.0\text{V}$ $I_C = -1.0\text{mA}, V_{CE} = -5.0\text{V}$ $I_C = -10\text{mA}, V_{CE} = -5.0\text{V}$	5086 5087 5086 5087 5086 5087	150 250 150 250 150 250	500 800	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$		-0.3	V	
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -1.0\text{mA}, V_{CE} = -5.0\text{V}$		-0.85	V	
<b>Small Signal Characteristics</b>						
$f_T$	Current Gain Bandwidth Product	$I_C = -500\mu\text{A}, V_{CE} = -5.0\text{V}, f = 20\text{MHz}$	40		MHz	
$C_{cb}$	Collector-Base Capacitance	$V_{CB} = -5.0\text{V}, I_E = 0, f = 100\text{KHz}$		4.0	pF	
$h_{fe}$	Small-Signal Current Gain	$I_C = -1.0\text{mA}, V_{CE} = -5.0\text{V}, f = 1.0\text{KHz}$	5086 5087	150 250	600 900	
NF	Noise Figure	$I_C = -100\mu\text{A}, V_{CE} = -5.0\text{V}$ $R_S = 3.0\text{k}\Omega, f = 1.0\text{KHz}$	5086 5087		3.0 2.0	dB dB
		$I_C = -20\mu\text{A}, V_{CE} = -5.0\text{V}$ $R_S = 10\text{k}\Omega$ $f = 10\text{Hz to } 15.7\text{KHz}$	5086 5087		3.0 2.0	dB dB

\* Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

**Thermal Characteristics**  $T_a=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Max.		Units
		2N5086 2N5087	*MMBT5087	
$P_D$	Total Device Dissipation	625	350	mW
	Derate above $25^\circ\text{C}$	5.0	2.8	mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	$^\circ\text{C/W}$

\* Device mounted on FR-4 PCB  $1.6" \times 1.6" \times 0.06"$

# Typical Characteristics

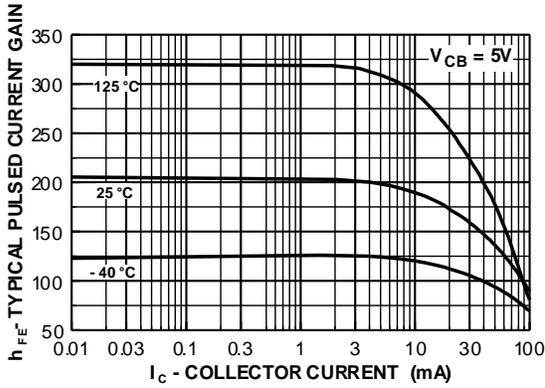


Figure 1. Typical Pulsed Current Gain vs Collector Current

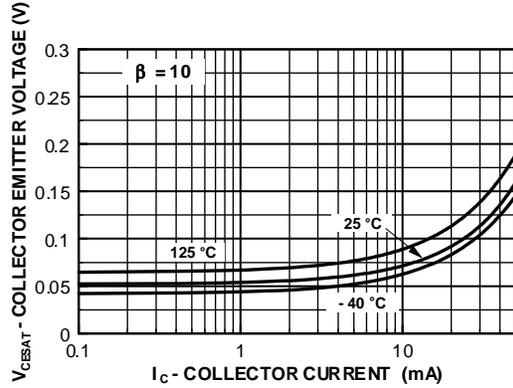


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

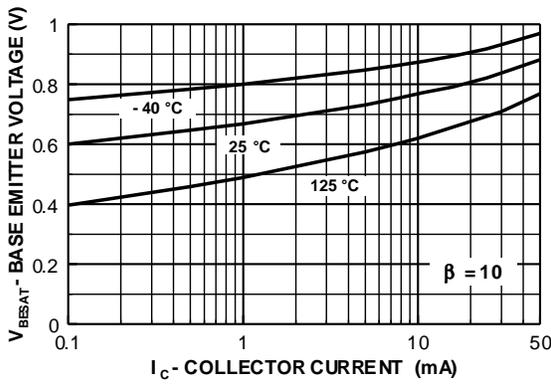


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

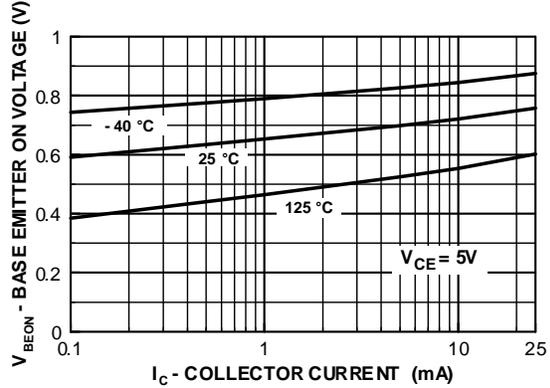


Figure 4. Base-Emitter On Voltage vs Collector Current

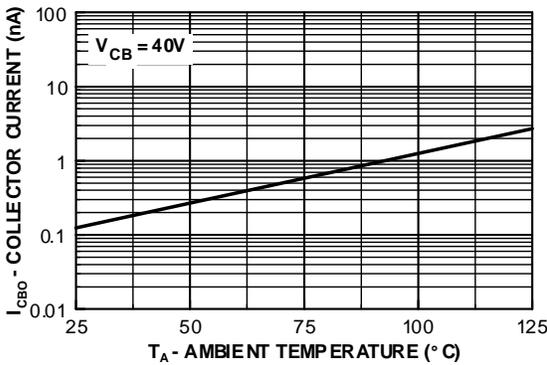


Figure 5. Collector Cutoff Current vs Ambient Temperature

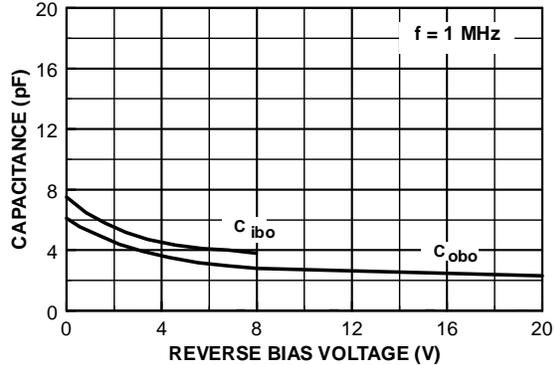


Figure 6. Input and Output Capacitance vs Reverse Voltage

Typical Characteristics (Continue)

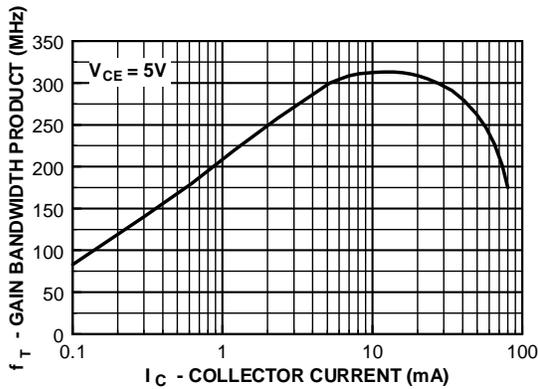


Figure 7. Gain Bandwidth Product vs Collector Current

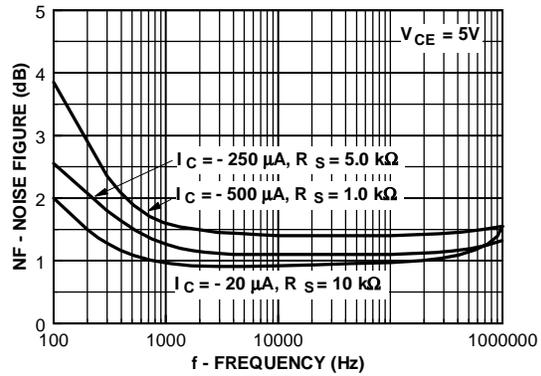


Figure 8. Noise Figure vs Frequency

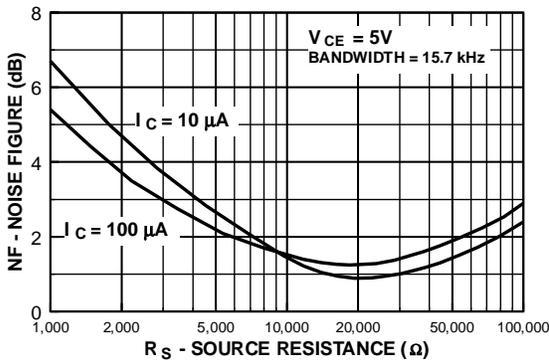


Figure 9. Wideband Noise Frequency vs Source Resistance

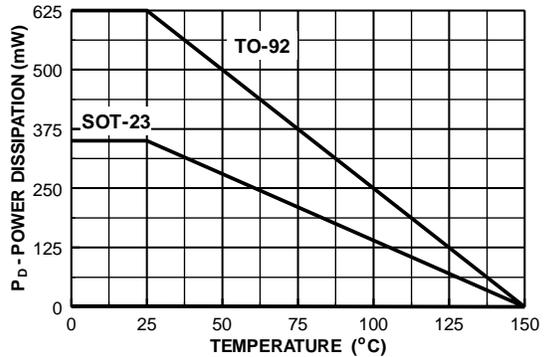


Figure 10. Power Dissipation vs Ambient Temperature

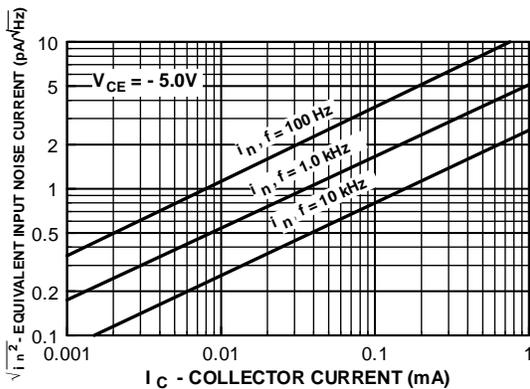


Figure 11. Equivalent Input Noise Current vs Collector Current

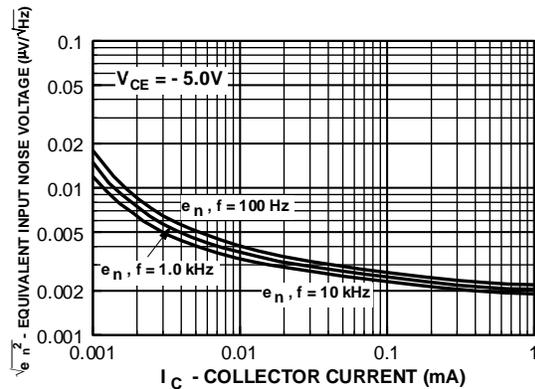


Figure 12. Equivalent Input Noise Voltage vs Collector Current

Typical Characteristics (Continue)

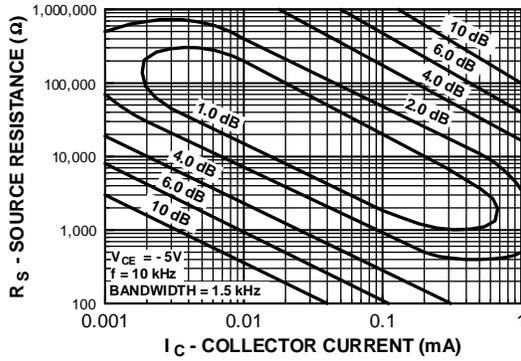


Figure 13. Contours of Constant Narrow Band Noise Figure

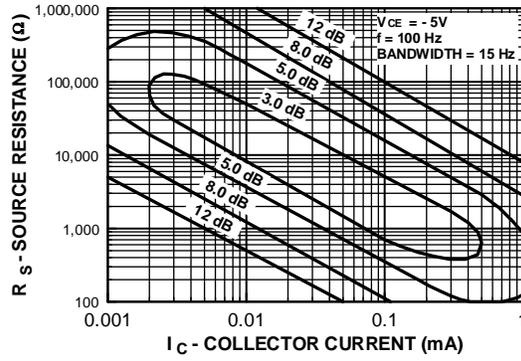


Figure 14. Contours of Constant Narrow Band Noise Figure

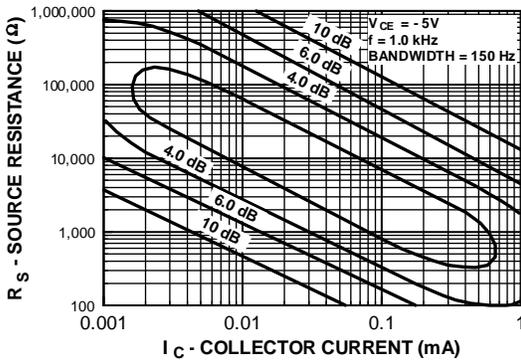


Figure 15. Contours of Constant Narrow Band Noise Figure

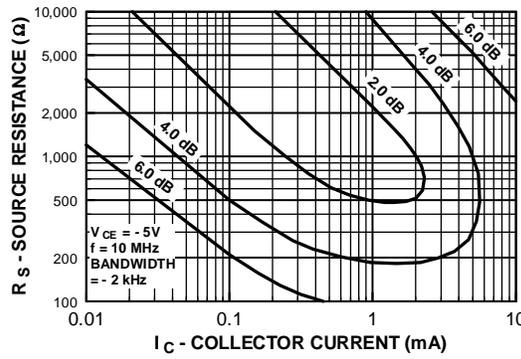
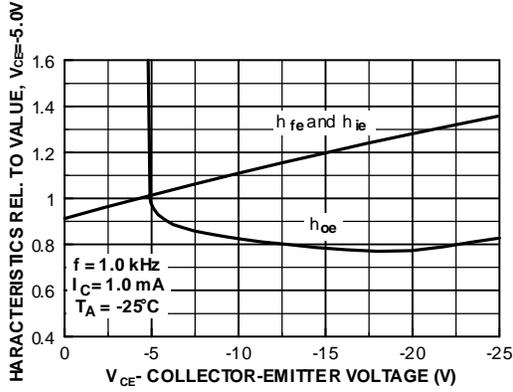
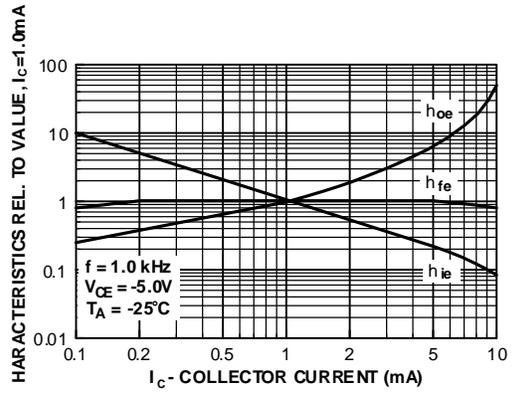


Figure 16. Contours of Constant Narrow Band Noise Figure

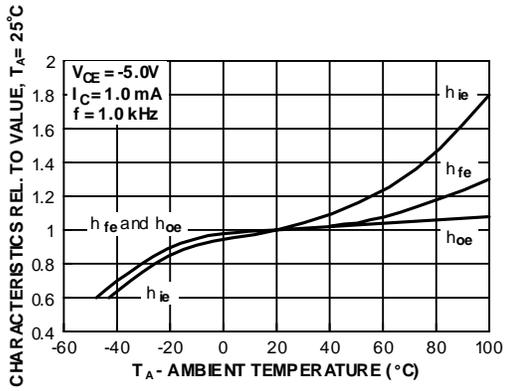
# Typical Common Emitter Characteristics (f = 1.0KHz)



Typical Common Emitter Characteristics



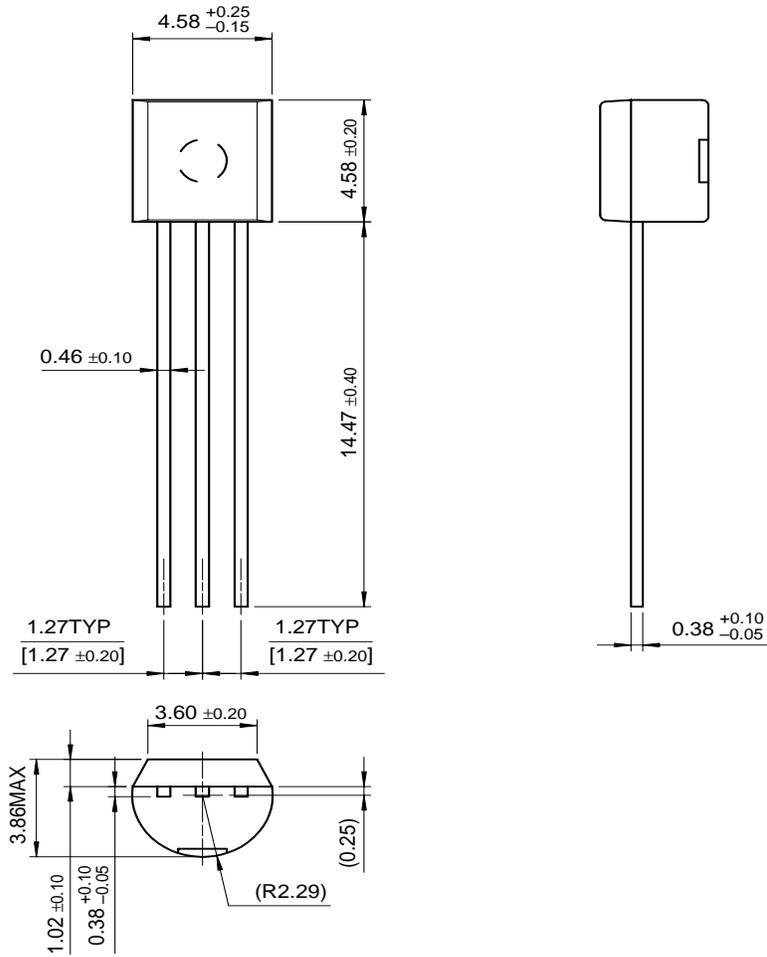
Typical Common Emitter Characteristics



Typical Common Emitter Characteristics

# Package Dimensions

## TO-92

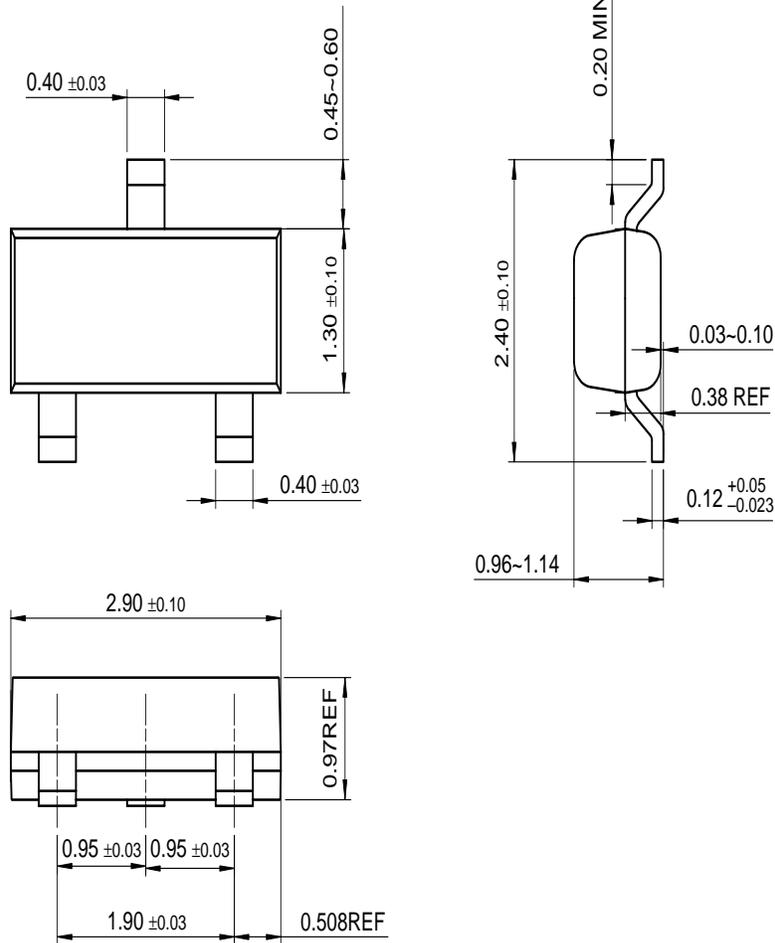


2N5086/2N5087/MMBT5087

Dimensions in Millimeters

# Package Dimensions (Continued)

## SOT-23



Dimensions in Millimeters

2N5086/2N5087/MMBT5087

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